International IOR Rectifier

21DQ04

SCHOTTKY RECTIFIER

2 Amp

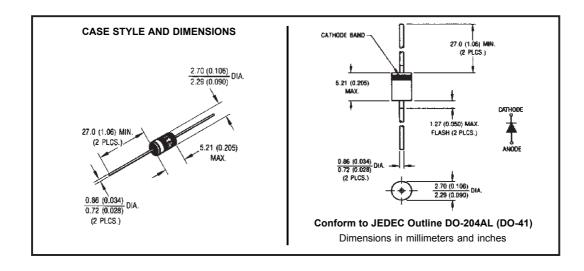
Major Ratings and Characteristics

Cha	racteristics	Values	Units
I _{F(AV)}	Rectangular waveform	2	А
V _{RRN}	Л	40	V
V _F	@2 Apk, T _J = 125°C	0.5	V
T _J	range	- 40 to 150	°C

Description/Features

The 21DQ04 axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- Low profile, axial leaded outline
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free plating



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Voltage Ratings

Part number	21DQ04	
V _R Max. DC Reverse Voltage (V)	40	
V _{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters		21DQ04	Units	Conditions		
I _{F(AV)} Max. Average Forward Current		2	Α	50% duty cycle @ T _C = 112°C, rectangular wave fo		
	* See Fig. 4					
I _{FSM}	Max. Peak One Cycle Non-Repetitive	420	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with rated V _{RRM} applied	
	Surge Current *See Fig. 6	70		10ms Sine or 6ms Rect. pulse		
E _{AS} Non-Repetitive Avalanche Energy		5.0	mJ	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.0 \text{Amps}, L = 10 \text{mH}$		
I _{AR} Repetitive Avalanche Current		1.0	А	Current decaying linearly to zero in 1 μ sec Frequency limited by T_J max. $V_A = 1.5 \text{ x } V_R$ typical		

Electrical Specifications

Parameters		21DQ04		Units	Conditions	
		Тур.	Max.	Office	Conditions	
V _{FM}	Max. Forward Voltage Drop	0.49	0.55	V	@ 2A	T,= 25 °C
	(1)	0.60	0.65	V	@ 4A	1 _J = 25 0
		0.42	0.5	V	@ 2A	T = 425 °C
		0.56	0.62	V	@ 4A	T _J = 125 °C
I _{RM}	Max. Reverse Leakage Current	0.01	0.50	mA	T _J = 25 °C	
	(1)	5.2	10	mA	T _J = 125 °C	$V_R = \text{rated } V_R$
C _T	Typical Junction Capacitance	130		pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C	
L _s	Typical Series Inductance	8.	0	nH	Measured le	ead to lead 5mm from package body

⁽¹⁾ Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

	Parameters	21DQ04	Units	Conditions
T_J	Max. Junction Temperature Range (*)	-40 to 150	°C	
T _{stg}	Max. Storage Temperature Range	-40 to 150	°C	
R _{thJA}	Max. Thermal Resistance Junction to Ambient	100	°C/W	DC operation Without cooling fin
R _{thJL}	Typical Thermal Resistance Junction to Lead	25	°C/W	DC Operation (* See Fig. 4)
wt	Approximate Weight	0.33(0.012)	g (oz.)	
	Case Style	DO-204AL(DO-41)		

 $[\]frac{\text{(*)}}{\text{dTj}} < \frac{1}{\text{Rth(j-a)}} \text{ thermal runaway condition for a diode on its own heatsink}$

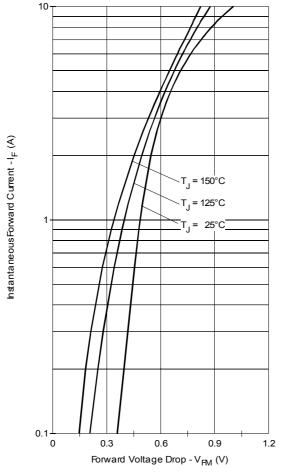


Fig. 1 - Maximum Forward Voltage Drop Characteristics

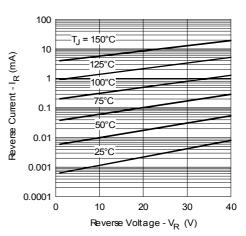


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

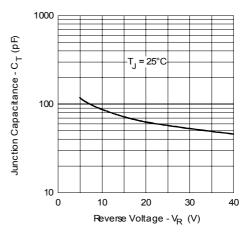


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

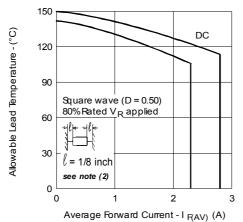


Fig. 4 - Maximum Allowable Lead Temperature Vs. Average Forward Current

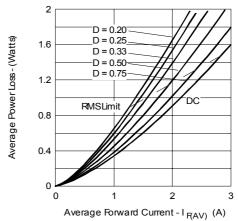


Fig. 5 - Forward Power Loss Characteristics

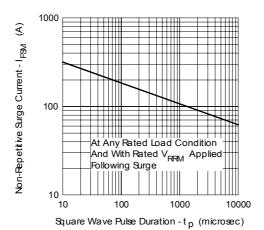


Fig. 6 - Maximum Non-Repetitive Surge Current

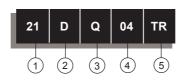
(2) Formula used: $T_L = T_J - (Pd + Pd_{REV}) \times R_{th,JL}$; $Pd = Forward Power Loss = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 5); $Pd_{REV} = Inverse Power Loss = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\%$ rated V_R

21DQ04

Bulletin PD-20707 rev. D 11/04

Ordering Information Table

Device Code



- 21 = 2.1A (Axial and small packages - Current is x10)

2 - D = DO-41 package

Q = Schottky Q.. SeriesO4 = Voltage Rating : 40V

TR = Tape & Reel package (5000 pcs)

TB = Tape & Box package (Ammunition -3000 pcs)

- = Box package (1000 pcs)

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level and Lead-Free.

Qualification Standards can be found on IR's Web site.



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